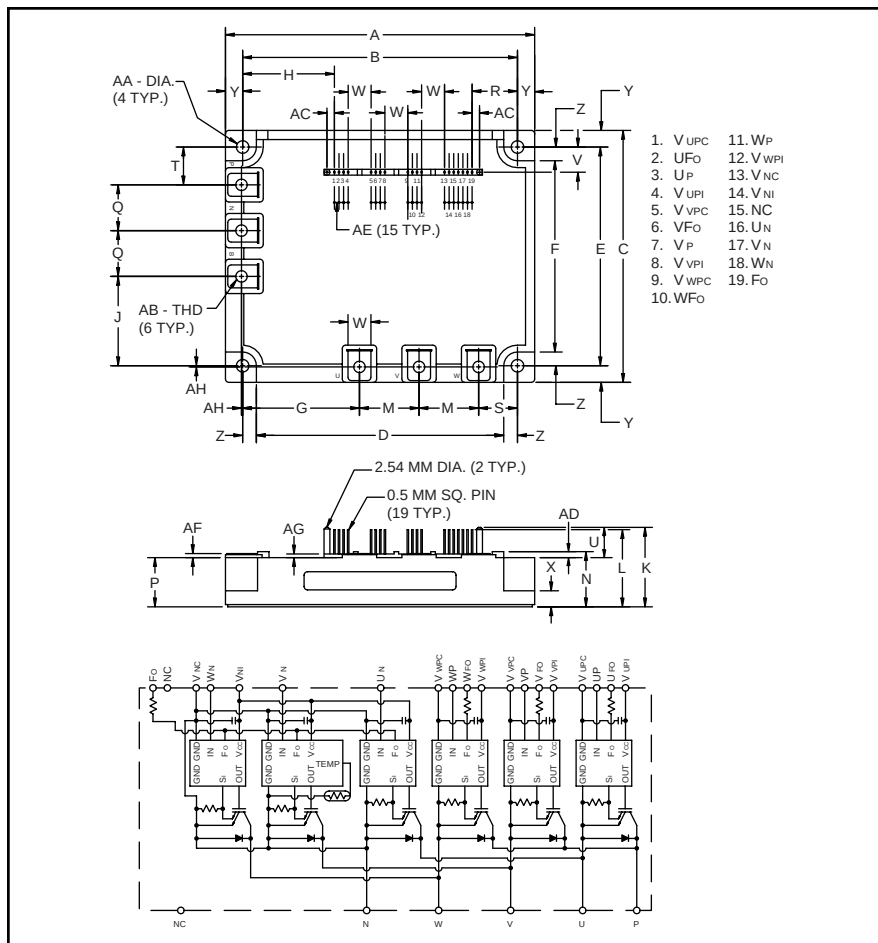


Intellimod™ Module

Three Phase
IGBT Inverter Output
150 Amperes/1200 Volts



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	5.31±0.04	135.0±1.0
B	4.74±0.02	120.5±0.5
C	4.33±0.04	110.0±1.0
D	4.27	108.5
E	3.76±0.02	95.5±0.5
F	3.29	83.5
G	2.01	51.0
H	1.602	40.68
J	1.54	39.0
K	1.37	34.7
L	1.33	33.7
M	1.02	26.0
N	0.95 +0.06/-0.0	24.1 +1.5/-0.0
P	0.85	21.5
Q	0.79	20.0
R	0.780	19.82

Dimensions	Inches	Millimeters
S	0.69	17.5
T	0.65	16.5
U	0.52	13.2
V	0.43	11.0
W	0.39	10.0
X	0.16	4.0
Y	0.285	7.25
Z	0.24	6.0
AA	0.22 Dia.	Dia. 5.5
AB	Metric M5	M5
AC	0.128	3.22
AD	0.10	2.6
AE	0.08	2.0
AF	0.07	1.8
AG	0.06	1.6
AH	0.02	0.5



Description:

Powerex Intellimod™ Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free-wheel diode power devices.

Features:

- ☐ Complete Output Power Circuit
- ☐ Gate Drive Circuit
- ☐ Protection Logic
 - Short Circuit
 - Over Current
 - Over Temperature
 - Under Voltage
- ☐ Low Loss Using 4th Generation IGBT Chip

Applications:

- ☐ Inverters
- ☐ UPS
- ☐ Motion/Servo Control
- ☐ Power Supplies

Ordering Information:

Example: Select the complete part number from the table below -i.e. PM150CSD120 is a 1200V, 150 Ampere Intellimod™ Intelligent Power Module.

Type	Current Rating Amperes	V _{CES} Volts (x 10)
PM	150	120

PM150CSD120
Intellimod™ Module
Three Phase IGBT Inverter Output
150 Amperes/1200 Volts

Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	PM150CSD120	Units
Power Device Junction Temperature	T_j	-20 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Case Operating Temperature*	T_C	-20 to 100	$^\circ\text{C}$
Mounting Torque, M5 Mounting Screws	—	31	in-lb
Mounting Torque, M5 Main Terminal Screws	—	31	in-lb
Module Weight (Typical)	—	920	Grams
Supply Voltage Protected by OC and SC ($V_D = 13.5 - 16.5\text{V}$, Inverter Part) $T_j = 125^\circ\text{C}$	$V_{CC(prot.)}$	800	Volts
Isolation Voltage, AC 1 minute, 60Hz Sinusoidal	V_{ISO}	2500	Volts

IGBT Inverter Sector

Collector-Emitter Voltage ($V_D = 15\text{V}$, $V_{CIN} = 15\text{V}$)	V_{CES}	1200	Volts
Collector Current, $\pm$ ($T_C = 25^\circ\text{C}$)	I_C	150	Amperes
Peak Collector Current, $\pm$ ($T_C = 25^\circ\text{C}$)	I_{CP}	300	Amperes
Supply Voltage (Applied between P - N)	V_{CC}	800	Volts
Supply Voltage, Surge (Applied between P - N)	$V_{CC(surge)}$	1000	Volts
Collector Dissipation ($T_C = 25^\circ\text{C}$)	P_C	781	Watts

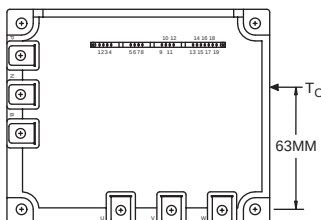
Control Sector

Supply Voltage Applied between ($V_{UP1}-V_{UPC}$, $V_{VP1}-V_{VPC}$, $V_{WP1}-V_{WPC}$, $V_{N1}-V_{NC}$)	V_D	20	Volts
Input Voltage Applied between (U_P-V_{UPC} , V_P-V_{VPC} , W_P-V_{WPC} , U_N-V_{NC} , W_N-V_{NC})	V_{CIN}	20	Volts
Fault Output Supply Voltage (Applied between $U_{FO}-V_{UPC}$, $V_{FO}-V_{VPC}$, $W_{FO}-V_{WPC}$, F_O-V_{NC})	V_{FO}	20	Volts
Fault Output Current (U_{FO} , V_{FO} , W_{FO} , F_O)	I_{FO}	20	mA

Electrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector Cutoff Current	I_{CES}	$V_{CE} = V_{CES}$, $T_j = 25^\circ\text{C}$, $V_D = 15\text{V}$, $V_{CIN} = 15\text{V}$	—	—	1.0	mA
		$V_{CE} = V_{CES}$, $T_j = 125^\circ\text{C}$, $V_D = 15\text{V}$, $V_{CIN} = 15\text{V}$	—	—	10	mA
Diode Forward Voltage	V_{EC}	$-I_C = 150\text{A}$, $V_D = 15\text{V}$, $V_{CIN} = 15\text{V}$	—	2.5	3.5	Volts
Collector-Emitter	$V_{CE(sat)}$	$V_D = 15\text{V}$, $V_{CIN} = 0\text{V}$, $I_C = 150\text{A}$, Pulsed, $T_j = 25^\circ\text{C}$	—	2.4	3.2	Volts
Saturation Voltage		$V_D = 15\text{V}$, $V_{CIN} = 0\text{V}$, $I_C = 150\text{A}$, Pulsed, $T_j = 125^\circ\text{C}$	—	2.1	2.8	Volts
Inductive Load	t_{on}		0.5	1.0	2.5	μS
Switching Times	t_{rr}	$V_D = 15\text{V}$, $V_{CIN} = 0 \sim 15\text{V}$	—	0.15	0.3	μS
	$t_{C(on)}$	$V_{CC} = 600\text{V}$, $I_C = 150\text{A}$	—	0.4	1.0	μS
	t_{off}	$T_j = 125^\circ\text{C}$, Inductive Load	—	2.5	3.5	μS
	$t_{C(off)}$		—	0.7	1.2	μS

* T_C Measure Point



PM150CSD120
Intellimod™ Module
Three Phase IGBT Inverter Output
150 Amperes/1200 Volts

Electrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Control Sector						
Over Current Trip Level ($V_D = 15\text{V}$)	OC	$T_j = 25^\circ\text{C}$	282	410	—	Amperes
		$T_j = 125^\circ\text{C}$	200	—	—	Amperes
Short Circuit Trip Level	SC	$-20^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $V_D = 15\text{V}$	—	540	—	Amperes
Over Current Delay Time	$t_{\text{off}}(\text{OC})$	$V_D = 15\text{V}$	—	10	—	μS
Over Temperature Protection ($V_D = 15\text{V}$)	OT	Trip Level	111	118	125	$^\circ\text{C}$
(Lower Arm)	OT_R	Reset Level	—	100	—	$^\circ\text{C}$
Supply Circuit Under Voltage Protection	UV	Trip Level	11.5	12.0	12.5	Volts
($-20 \leq T_j \leq 125^\circ\text{C}$)	UV_R	Reset Level	—	12.5	—	Volts
Circuit Current	I_D	$V_D = 15\text{V}$, $V_{\text{CIN}} = 15\text{V}$, $V_{N1}-V_{\text{NC}}$	—	45	62	mA
		$V_D = 15\text{V}$, $V_{\text{CIN}} = 15\text{V}$, $V_{\text{XP1}}-V_{\text{XPC}}$	—	15	20	mA
Input ON Threshold Voltage	$V_{\text{CIN(on)}}$	Applied between U_P-V_{UPC} , V_P-V_{VPC} ,	1.2	1.5	1.8	Volts
Input OFF Threshold Voltage	$V_{\text{CIN(off)}}$	W_P-V_{WPC} , U_N , V_N , W_N-V_{NC}	1.7	2.0	2.3	Volts
Fault Output Current*	$I_{\text{FO(H)}}$	$V_D = 15\text{V}$, $V_{\text{CIN}} = 15\text{V}$	—	—	0.01	mA
	$I_{\text{FO(L)}}$	$V_D = 15\text{V}$, $V_{\text{CIN}} = 15\text{V}$	—	10	15	mA
Minimum Fault Output Pulse Width*	t_{FO}	$V_D = 15\text{V}$	1.0	1.8	—	mS

*Fault output is given only when the internal OC, SC, OT and UV protections schemes of either upper or lower device operate to protect it.

Thermal Characteristics

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	$R_{\text{th(j-c)Q}}$	Each IGBT	—	—	0.16	$^\circ\text{C/Watt}$
	$R_{\text{th(j-c)F}}$	Each FWDi	—	—	0.24	$^\circ\text{C/Watt}$
	$R_{\text{th(j-c')Q}}$	Each IGBT**	—	—	$0.10^\dagger$	$^\circ\text{C/Watt}$
	$R_{\text{th(j-c')F}}$	Each FWDi**	—	—	$0.16^\dagger$	$^\circ\text{C/Watt}$
Contact Thermal Resistance	$R_{\text{th(c-f)}}$	Case to Fin Per Module, Thermal Grease Applied	—	—	0.018	$^\circ\text{C/Watt}$

** T_C measured point is just under chip.

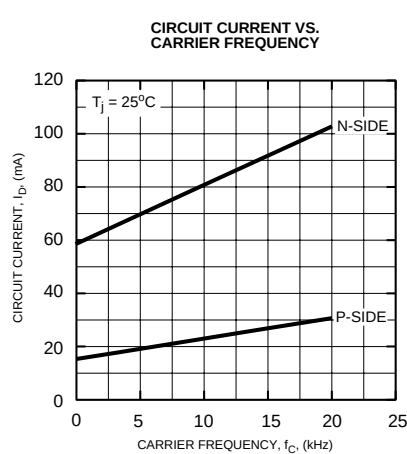
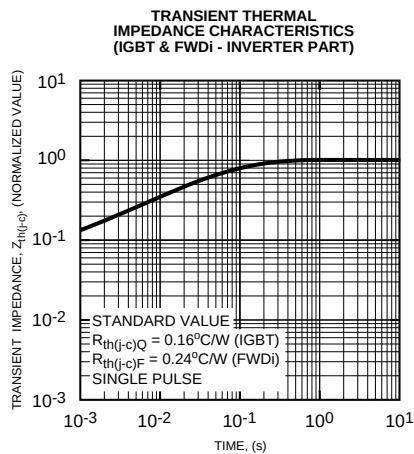
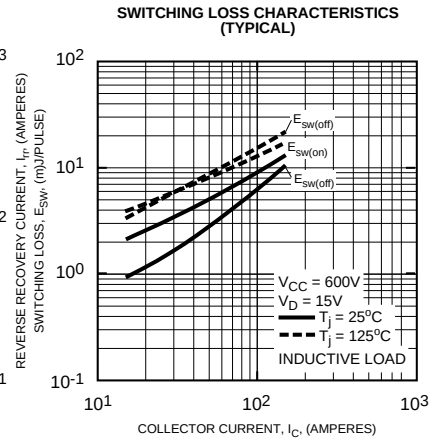
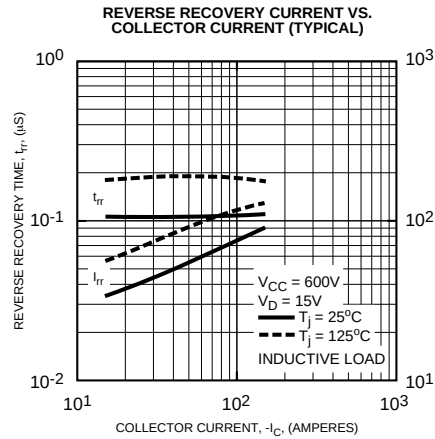
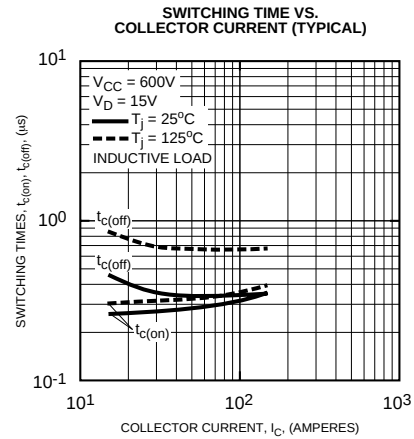
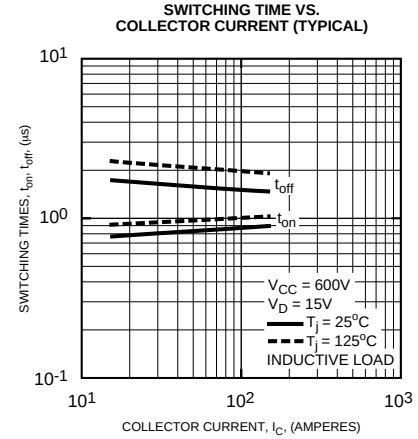
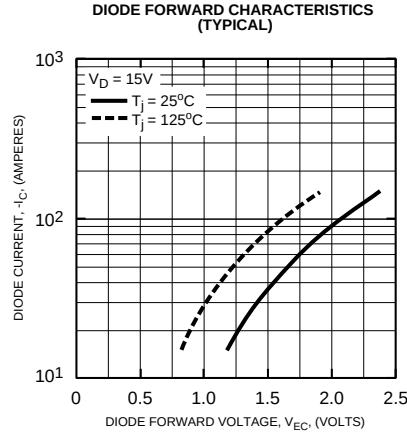
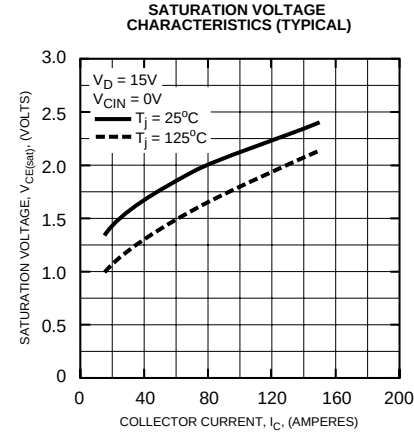
$\dagger$ If you use this value, $R_{\text{th(f-a)}}$ should be measured just under the chips.

Recommended Conditions for Use

Characteristic	Symbol	Condition	Value	Units
Supply Voltage	V_{CC}	Applied across P-N Terminals	0 ~ 800	Volts
Control Supply Voltage***	V_D	Applied between $V_{\text{UP1}}-V_{\text{UPC}}$, $V_{N1}-V_{\text{NC}}$, $V_{\text{VP1}}-V_{\text{VPC}}$, $V_{\text{WP1}}-V_{\text{WPC}}$	15 ± 1.5	Volts
Input ON Voltage	$V_{\text{CIN(on)}}$	Applied between U_P-V_{UPC} , V_P-V_{VPC} ,	0 ~ 0.8	Volts
Input OFF Voltage	$V_{\text{CIN(off)}}$	W_P-V_{WPC} , U_N , V_N , W_N-V_{NC}	$4.0 \sim V_D$	Volts
PWM Input Frequency	f_{PWM}	Using Application Circuit	0 ~ 20	kHz
Minimum Dead Time	t_{DEAD}	Input Signal	≥ 3.0	μS

*** With ripple satisfying the following conditions: dv/dt swing $\leq \pm 5\text{V}/\mu\text{s}$, Variation $\leq 2\text{V}$ peak to peak.

PM150CSD120
Intellimod™ Module
Three Phase IGBT Inverter Output
150 Amperes/1200 Volts





Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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